L Number	Hits	Search Text	DB	Time stamp
1	1	6037712.pn.	USPAT;	2003/07/12 17:54
	:		US-PGPUB	
-	65		USPAT;	2003/07/12 10:47
		near2 (nitride oxynitride)))) and ((organic near2 (element layer	US-PGPUB	
		film electroluminecen\$2 EL)) (light near2 (emitting emission		
		emitter))) and (partition rampart ridge rib barrier wall spacer) and 313/498-512.ccls.		
_	302	(TFT transistor) and (insulat\$3 dielectric) and ((organic near2	USPAT;	2003/07/01 10:46
	302	(element layer film electroluminecen\$2 EL)) (light near2 (emitting	US-PGPUB	2003/07/01 10.40
		emission emitter))) and (partition rampart ridge rib barrier wall	00 1 01 00	
		spacer) and 313/495-512.ccls.		
-	2	("4266223" "5384517").PN.	USPAT	2003/06/30 16:29
-	17	5640067.URPN.	USPAT	2003/06/30 16:29
-	10	(USPAT	2003/06/30 16:39
		"5643826" "5731613" "5897328" "5923962" "6048758"		
	_	"2001/0004121").PN.		
-	2	6461899.URPN.	USPAT	2003/06/30 16:43
-	246	((TFT transistor) and (insulat\$3 dielectric) and ((organic near2	USPAT;	2003/07/01 11:00
		(element layer film electroluminecen\$2 EL)) (light near2 (emitting	US-PGPUB	
		emission emitter))) and (partition rampart ridge rib barrier wall spacer) and 313/495-512.ccls.) not @ad>20011108		
_	1620	((TFT transistor) and (insulat\$3 dielectric) and ((organic near2	USPAT;	2003/07/01 11:03
	1020	(element layer film electroluminecen\$2 EL)) (light near2 (emitting	US-PGPUB	2003/07/01 11:03
		emission emitter))) and (partition rampart ridge rib barrier wall	05 1 01 05	
		spacer) and 257/\$.ccls.) not @ad>20001110		
-	5408	((TFT transistor) and (insulat\$3 dielectric) and ((organic near2	USPAT;	2003/07/01 11:16
		(element layer film electroluminecen\$2 EL)) (light near2 (emitting	US-PGPUB	
		emission emitter))) and (partition rampart ridge rib barrier wall		
		spacer)) not @ad>20001110		
-	73816	257/\$4.ccls.	USPAT;	2003/07/01 11:06
	000	///	US-PGPUB	2002/07/04 44 06
-	999	(((TFT transistor) and (insulat\$3 dielectric) and ((organic near2	USPAT;	2003/07/01 11:06
		(element layer film electroluminecen\$2 EL)) (light near2 (emitting emission emitter))) and (partition rampart ridge rib barrier wall	US-PGPUB	
		spacer)) not @ad>20001110) and 257/\$4.ccls.		
_	927	((TFT transistor) and (insulat\$3 dielectric) and ((organic near2	USPAT;	2003/07/01 12:38
		((light near2 (emitting emission emitter)) electroluminecen\$2 EL))	US-PGPUB	=====================================
		(light near3 (layer element film) near2 (emitting emission		
		emitter))) and (partition rampart ridge rib barrier wall spacer)) not		
		@ad>20001110		
-	77791	313/495-512.ccls. 257/\$3.ccls.	USPAT;	2003/07/01 11:56
			US-PGPUB	
-	361		USPAT;	2003/07/01 11:56
		((light near2 (emitting emission emitter)) electroluminecen\$2 EL))	US-PGPUB	
		(light near3 (layer element film) near2 (emitting emission emitter))) and (partition rampart ridge rib barrier wall spacer)) not		
		@ad>20001110) and (313/495-512.ccls. 257/\$3.ccls.)		}
_	8	((TFT transistor) and (insulat\$3 dielectric) and ((organic near2	EPO; JPO;	2003/07/01 12:41
	· ·	((light near2 (emitting emission emitter)) electroluminecen\$2 EL))	DERWENT	2005,07,01 12:11
		(light near3 (layer element film) near2 (emitting emission		
		emitter))) and (partition rampart ridge rib barrier wall spacer)) not		
		@pd>20001110		
-	22		EPO; JPO;	2003/07/03 16:02
		((EL electroluminescen\$2 (light near2 (emitting emission	DERWENT	
		emitter))) near3 (device display panel element)) and (partition		
	COF	barrier rib spacer rampart wall)	LICDAT:	2002/02/02 17 17
-	685		USPAT;	2003/07/03 17:15
		((EL electroluminescen\$2 (light near2 (emitting emission emitter))) near3 (device display panel element)) and (partition	US-PGPUB	
		barrier rib spacer rampart wall) and (313/495-512.ccls.	,	
		257/\$3.ccls.)		
		25//\$3.CCIS.)	L	<u></u>

-	369	(((TFT transistor) same (insulat\$3 insolat\$3 isolat\$3 dielectric))	USPAT;	2003/07/03 16:46
		and ((EL electroluminescen\$2 (light near2 (emitting emission	US-PGPUB	
		emitter))) near3 (device display panel element)) and (partition		
		barrier rib spacer rampart wall) and (313/495-512.ccls.		
		257/\$3.ccls.)) not @ad>20001110		
-	24		USPAT	2003/07/03 16:36
		"5021848" "5053842" "5071782" "5078498" "5146426"		
		"5202576" "5323042" "5350937" "5594569" "5633519"		•
		"5643826" "5923962" "5939731" "5965915" "6055034"		
		"6166414" "6172671" "6198133" "6281552").PN.		
1 -	2133	semiconductor adj energy adj laboratory\$.as.	USPAT;	2003/07/03 16:45
			US-PGPUB	
-	211		USPAT;	2003/07/03 16:47
		and ((EL electroluminescen\$2 (light near2 (emitting emission	US-PGPUB	
		emitter))) near3 (device display panel element)) and (partition		
		barrier rib spacer rampart wall) and (313/495-512.ccls.		
		257/\$3.ccls.)) not @pd>20001110		
-	2	("5742129" "5804917").PN.	USPAT	2003/07/03 17:16
-	_2	("5631664" "5684365").PN.	USPAT	2003/07/03 17:17
-	59	5684365.URPN.	USPAT	2003/07/03 17:17
-	1118	313/504.ccls.	USPAT;	2003/07/03 17:18
			US-PGPUB	
-	6	("4015166" "5550066" "5684365" "5742129" "6072450"	USPAT	2003/07/03 17:19
	204	"6091382").PN.		
-	204	313/504.ccls. and transistor	USPAT;	2003/07/07 10:37
	_	(#4724622# 1 #FF40000# 1 #FF6F742# 1 #F0F0F00# 1	US-PGPUB	2002/07/07 40 24
-	5	("4734623" "5518808" "5565742" "5859508"	USPAT	2003/07/07 10:34
	,	"5936347").PN.	LICDAT	2002/07/07 40-25
-	3	("5352543" "5371434" "5384517").PN.	USPAT USPAT	2003/07/07 10:35
} <u> </u>	1 11	"5156924".PN. 5352543.URPN.	USPAT	2003/07/07 10:36 2003/07/07 10:36
1	478	313/498-512.ccls. and transistor	USPAT;	2003/07/07 10:36
	7/0	515/430-512.ccis. and danisistor	US-PGPUB	2003/07/07 10.37
_	122	313/504.ccls. and TFT	USPAT;	2003/07/07 10:42
		,,	US-PGPUB	2000,07,07
_	4	("5004950" "5194290" "5523770" "5804917").PN.	USPAT	2003/07/07 10:41
-	581	313/504.ccls. and (carbon diamond graphite)	USPAT;	2003/07/07 10:42
		, , , , , , , , , , , , , , , , , , ,	US-PGPUB	
-	280	313/504.ccls. and ((carbon diamond graphite) with (dielectric	USPAT;	2003/07/07 10:48
		insulat\$3 layer film coat\$3))	US-PGPUB	
-	4	("5004950" "5194290" "5523770" "5804917").PN.	USPAT	2003/07/07 10:46
-	3	6114183.URPN.	USPAT	2003/07/07 10:46
-	445	345/92.ccls.	USPAT;	2003/07/07 10:48
			US-PGPUB	
-	65	, , , , , , , , , , , , , , , , , , , ,	USPAT;	2003/07/07 11:00
		near2 (emitting emission emitter))) near3 (element device display	US-PGPUB	
		panel))		
-	366	345/76-81.ccls. and (((organic near3 (EL electroluminescen\$2))	USPAT;	2003/07/07 11:04
		(light near2 (emitting emission emitter))) near3 (element device	US-PGPUB	
		display panel))		2002/07/27 : : : =
-	79	345/76-81.ccls. and (((organic near3 (EL electroluminescen\$2))	USPAT;	2003/07/07 11:05
		(light near2 (emitting emission emitter))) near3 (element device	US-PGPUB	
	346	display panel)) and (rampart barrier rib spacer partition ridge)	LICEAT	2002/07/42 42 24
-	340	(insulat\$3 dielectric SIN SION "Si.sub.3 N.sub.4" (silicon near2	USPAT;	2003/07/12 13:24
		(nitride oxynitride))) and (transistor TFT thin-film-transistor) and	US-PGPUB	
		((EL electroluminescen\$2 (light near2 (emitting emission emissive		
₋	1010	emitter))) near2 (element layer film)) and 313/500-512.ccls.	LICDAT:	2002/07/42 44:20
-	1010	(insulat\$3 dielectric SIN SION "Si.sub.3 N.sub.4" (silicon near2	USPAT;	2003/07/12 11:39
		(nitride oxynitride))) and (transistor TFT thin-film-transistor) and	US-PGPUB	
		((EL electroluminescen\$2 (light near2 (emitting emission emissive		
L	L	emitter))) near2 (element layer film)) and 257/\$.ccls.	L	1

-	784	(insulat\$3 dielectric SIN SION "Si.sub.3 N.sub.4" (silicon near2 (nitride oxynitride))) and (transistor TFT thin-film-transistor) and	USPAT; US-PGPUB	2003/07/12 11:42
		((EL electroluminescen\$2 (light near2 (emitting emission emissive	05 10105	
		emitter))) near2 (element layer film)) and 257/\$3.ccls.		
-	481	(insulat\$3 dielectric SIN SION "Si.sub.3 N.sub.4" (silicon near2	USPAT;	2003/07/12 11:43
		(nitride oxynitride))) and (transistor TFT thin-film-transistor) and	US-PGPUB	
		((EL electroluminescen\$2 (light near2 (emitting emission emissive		
		emitter))) near2 (element layer film)) and (organic OLED) and		
	220	257/\$3.ccls.	LICOAT	2002/07/42 42 04
-	228	(insulat\$3 dielectric SIN SION "Si.sub.3 N.sub.4" (silicon near2 (nitride oxynitride))) and (transistor TFT thin-film-transistor) and	USPAT;	2003/07/12 12:04
		((EL electroluminescen\$2 (light near2 (emitting emission emissive	US-PGPUB	
		emitter))) near2 (OLED organic) near2 (element layer film)) and		
		257/\$3.ccls.		
-	3	("5294870" "5552547" "5641611").PN.	USPAT	2003/07/12 11:51
-	172	(insulat\$3 dielectric SIN SION "Si.sub.3 N.sub.4" (silicon near2	USPAT;	2003/07/12 12:06
		(nitride oxynitride))) and (transistor TFT thin-film-transistor) and	US-PGPUB	
		((EL electroluminescen\$2 (light near2 (emitting emission emissive		
		emitter))) near2 (OLED organic) near2 (element layer film)) and		
_	0	345/\$3.ccls. (insulat\$3 dielectric SIN SION "Si.sub.3 N.sub.4" (silicon near2	USPAT;	2003/07/12 12:06
	"	(nitride oxynitride))) and (transistor TFT thin-film-transistor) and	US-PGPUB	2003/07/12 12:06
		((EL electroluminescen\$2 (light near2 (emitting emission emissive	05 / 0/ 05	
		emitter))) near2 (OLED organic) near2 (element layer film)) and		
		169.3/\$3.ccls.		
-	134	(insulat\$3 dielectric SIN SION "Si.sub.3 N.sub.4" (silicon near2	USPAT;	2003/07/12 12:07
		(nitride oxynitride))) and (transistor TFT thin-film-transistor) and	US-PGPUB	
		((EL electroluminescen\$2 (light near2 (emitting emission emissive		
		emitter))) near2 (OLED organic) near2 (element layer film)) and 438/\$3.ccls.		
_	162	((insulat\$3 dielectric SIN SION "Si.sub.3 N.sub.4" (silicon near2	USPAT;	2003/07/12 12:07
		(nitride oxynitride))) and (transistor TFT thin-film-transistor) and	US-PGPUB	2005/07/12 12:07
		((EL electroluminescen\$2 (light near2 (emitting emission emissive		
		emitter))) near2 (OLED organic) near2 (element layer film)) and		
		345/\$3.ccls.) not ((insulat\$3 dielectric SIN SION "Si.sub.3		
		N.sub.4" (silicon near2 (nitride oxynitride))) and (transistor TFT		
		thin-film-transistor) and ((EL electroluminescen\$2 (light near2 (emitting emission emissive emitter))) near2 (OLED organic) near2		
		(element layer film)) and 257/\$3.ccls.)		
-	784	(DLC diamond-like (diamond near2 like) carbon) and ((EL	USPAT;	2003/07/12 13:26
		electroluminescen\$2 (light near2 (emitting emission emissive	US-PGPUB	2005,07,22 20.20
		emitter))) near2 (element layer film)) and 313/500-512.ccls.		
-	520	(DLC diamond-like (diamond near2 like) carbon) and ((EL	USPAT;	2003/07/12 13:26
		electroluminescen\$2 (light near2 (emitting emission emissive	US-PGPUB	
		emitter))) near2 (organic OLED) near2 (element layer film)) and		
_	1	313/500-512.ccls. 5952708.pn.	USPAT;	2003/07/12 12:20
	•	3332730.μπ.	USPAT; US-PGPUB	2003/07/12 13:39
_	62	((insulat\$3 dielectric) same (DLC diamond-like carbide (diamond	USPAT;	2003/07/12 14:05
		near2 like) carbon)) and ((EL electroluminescen\$2 (light near2	US-PGPUB	-300,07,22 21.05
		(emitting emission emissive emitter))) near2 (organic OLED) near2		
		(element layer film)) and 313/500-512.ccls.		
-	70	((protect\$3) same (DLC diamond-like carbide (diamond near2 like)	USPAT;	2003/07/12 14:30
		carbon)) and ((EL electroluminescen\$2 (light near2 (emitting	US-PGPUB	
		emission emissive emitter))) near2 (organic OLED) near2 (element		
_	ا و	layer film)) and 313/500-512.ccls. ("5276380" "5294869" "5521465" "5587589" "5652067"	USPAT	2003/07/12 14:11
	7	(3276360 3294669 3321463 3387389 3632067 "5656508" "5693962" "5701055" "5773931").PN.	USPAT	2003/07/12 14:11
_	1	6037712.pn.	USPAT;	2003/07/12 17:54
		<u> </u>	US-PGPUB	
				•